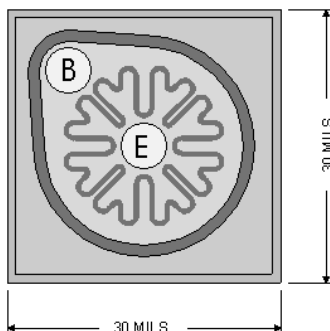


Chip Type 2C3501
Geometry 5620
Polarity NPN

Generic Packaged Parts:

**2N3498, 2N3499, 2N3500,
2N3501**


[Request Quotation](#)

Chip type **2C3501** by Semicoa Semiconductors provides performance similar to these devices.

Product Summary:

APPLICATIONS: Designed for switching and amplifier applications.

Part Numbers:

[2N3498](#), [2N3498L](#), [2N3499](#), [2N3499L](#), [2N3500](#),
[2N3500L](#), [2N3501](#), [2N3501L](#)

Features:

Mechanical Specifications		
Metallization	Top	Al - 22.5 kÅ min.
	Backside	Au - 6.5 kÅ nom.
Bonding Pad Size	Emitter	5.0 mils diameter
	Base	5.0 mils diameter
Die Thickness	8 mils nominal	
Chip Area	30 mils x 30 mils	
Top Surface	Silox Passivated	

Electrical Characteristics				
$T_A = 25^\circ\text{C}$				
Parameter	Test conditions	Min	Max	Unit
BV_{CEO}	$I_C = 10.0 \text{ mA}$, $I_B = 0$	150	---	V dc
BV_{CBO}	$I_C = 10 \text{ }\mu\text{A}$, $I_E = 0$	150	---	V dc
BV_{EBO}	$I_E = 10 \text{ }\mu\text{A}$, $I_C = 0$	6.0	---	V dc
I_{CBO}	$V_{CB} = 75 \text{ V}$, $I_E = 0$	---	50	nA
h_{FE}	$I_C = 150 \text{ mA dc}$, $V_{CE} = 10.0 \text{ V}$	100	300	---

Due to limitations of probe testing, only dc parameters are tested. This must be done with pulse width less than 300 μs , duty cycle less than 2%.